

10/045499

L Number	Hits	Search Text	DB	Time stamp
1	107858	strap\$3	USPAT; US-PGPUB; JPO	2003/04/07 09:35
2	42183	trench\$2	USPAT; US-PGPUB; JPO	2003/04/07 09:35
3	55491	dram\$1 or (dynamic adj random)	USPAT; US-PGPUB; JPO	2003/04/07 09:35
4	62032	polysilicon or polysi	USPAT; US-PGPUB; JPO	2003/04/07 09:36
5	292750	etch\$3	USPAT; US-PGPUB; JPO	2003/04/07 09:36
6	11159	sti or (shallow adj trench) or (trench adj isolation)	USPAT; US-PGPUB; JPO	2003/04/07 09:36
7	497	node adj (dielectric or insulat\$3)	USPAT; US-PGPUB; JPO	2003/04/07 09:37
8	518	strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3	USPAT; US-PGPUB; JPO	2003/04/07 09:37
9	339	(sti or (shallow adj trench) or (trench adj isolation)) and (strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3)	USPAT; US-PGPUB; JPO	2003/04/07 09:38
10	136	(node adj (dielectric or insulat\$3)) and ((sti or (shallow adj trench) or (trench adj isolation)) and (strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3))	USPAT; US-PGPUB; JPO	2003/04/07 09:38
11	382	(strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3) not ((node adj (dielectric or insulat\$3)) and ((sti or (shallow adj trench) or (trench adj isolation)) and (strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3)))	USPAT; US-PGPUB; JPO	2003/04/07 09:38
12	330	(node adj (dielectric or insulat\$3)) not (((node adj (dielectric or insulat\$3)) and ((sti or (shallow adj trench) or (trench adj isolation)) and (strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3))) or ((strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3) not ((node adj (dielectric or insulat\$3)) and ((sti or (shallow adj trench) or (trench adj isolation)) and (strap\$3 and trench\$2 and (dram\$1 or (dynamic adj random)) and (polysilicon or polysi) and etch\$3))))))	USPAT; US-PGPUB; JPO	2003/04/07 09:38